Office of the Registrar FORM 40 REV. 7/08

PURDUE UNIVERSITYREQUEST FOR ADDITION, EXPIRATION, OR REVISION OF AN UNDERGRADUATE COURSE (10000-40000 LEVEL)

EPARTMENT	Materials	Engineering
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EFFECTIVE SESSION Spring 2009

NSTRUCTIONS: Please check the items below	which describe the purpose of this re	quest.	
1. New course with supporting doc 2. Add existing course offered at a 3. Expiration of a course 4. Change in course number 5. Change in course title 6. Change in course credit/type PROPOSED: Subject Abbreviation MSE Course Number 270 Long Title Atomistic Materials Science Short Title Atom Mtls Sci	uments	7. Change in course attributes 8. Change in instructional hour 9. Change in course descriptio 10. Change in course requisites 11. Change in semesters offere 12. Transfer from one departme	d (department head signature only) int to another TERMS OFFERED Check All That Apply: Jummer Fall Spring CAMPUS(ES) INVOLVED Jalumet N. Central John Ed Tech Statewide John Wayne John John John John John John John John
Available Credit Range: Minimum Cr. Hrs (Check One) To Or Maximum Cr. Hrs. 3. Equivalent Credit: Yes No	Satisfactory/Unsatisfactory Only Repeatable Maximum Repeatable Credit: Credit by Examination Special Fees	Department 7. Variable Title 8. Honors 9. Full Time Privilege 10. Off Campus Exper	Instructor
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Calumet Department Head Date Fort Wayne Department Head Date	Calumet School Dean Fort Wayne School Dean	Date Date	:
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OFFICE OF THE REGISTRAR



Office of the Registrar FORM 40 REV. 7/08

PURDUE UNIVERSITY REQUEST FOR ADDITION, EXPIRATION, OR REVISION OF AN UNDERGRADUATE COURSE (10000-40000 LEVEL)

PARTMENT Materials Engineering EFFECTIVE SESSION Spring 2009				
INSTRUCTIONS: Please check the items below	v which describe the purpose of this re	equest.		
1. New course with supporting doc 2. Add existing course offered at a 3. Expiration of a course 4. Change in course number 5. Change in course title 6. Change in course credit/type PROPOSED: Subject Abbreviation MSE Course Number 270 Long Title Atomistic Materials Science Short Title Atom Mtls Sci	EXISTING: Subject Abbreviation Course Number	8. Change in ins 9. Change in cou 10. Change in cou 11. Change in ser 12. Transfer from	urse attributes (department head signature only) tructional hours urse description urse requisites mesters offered (department head signature only) one department to another TERMS OFFERED Check All That Apply: Summer Fall Spring CAMPUS(ES) INVOLVED Calumet N. Central Tech Statewide Ft. Wayne Indianapolis	
Abbreviated title will be entered	d by the Office of the Registrar if omitt	ed. (30 CHARACTERS ONLY)		
CREDIT TYPE 1. Fixed Credit: Cr. Hrs. 3 2. Variable Credit Range: Minimum Cr. Hrs (Check One) To Or Maximum Cr. Hrs. 3. Equivalent Credit: Yes No ScheduleType Minutes Per Mtg Week 1 ture 1 tation Presentation Presentation Laboratory Lab Prep Studio Distance Clinic Experiential Research Ind. Study Pract/Observ COURSE DESCRIPTION (INCLUDE REQUISITES)	Offered Allocated 16 100	7. Variable 8. Honor	stration Approval Type Department Instructor a Title	
Introductory course with an atomistic veiw point or include introduction to quantum mechanics, emph symmetry principles. Statistical mechanics developments	asis on understanding of metallic, ioni	c and covalent bonding. Crys	allography and statistical mechanics. Bonding topics stallography topics include crystal descriptions and	
Calumet Department Head Date	Calumet School Dean	Date		
Fort Wayne Department Head Date	Fort Wayne School Dean	Date		
Indianapolis Department Head Date	Indianapolis School Dean	Date		
Central Department Head Date	North Central Chancellor			
West Lafayette Department Head L Date	West/Lafayette College/School Dean	/ Date W	est Lafavette Registrar Date	

West Lafayette Registrar

Date

			

TO:

The Engineering Faculty

FROM:

The Faculty of the School of Materials Engineering

DATE:

March 1, 2008

RE:

New Undergraduate Course, MSE 270

The faculty of the School of Materials Engineering have approved the following new course. This action is now submitted to the Engineering Faculty with a recommendation for approval.

MSE 270

Atomistic Materials Science

Sem. 2. Class 3, Cr. 3.

Prerequisite: MA 261 and MA 265; Co-requisite: MSE 230 or consent of

instructor.

Description: Introductory course with an atomistic viewpoint on material properties. Three primary class sections: bonding, crystallography and statistical mechanics. Bonding topics include introduction to quantum mechanics, emphasis on understanding of metallic, ionic and covalent bonding. Crystallography topics include crystal descriptions and symmetry principles. Statistical mechanics developed with application to electronic and thermodynamic properties.

Reason:

This class is currently (Spring 2008) offered as MSE 497S with an enrollment of 35 students. Updated School of Materials Engineering curriculum (EFD 50-07) will make this a required course for students entering MSE. This course represents a new emphasis on developing a fundamental understanding of atomistic material science, which is consistent with undergraduate topics covered by peer institutions, increased interest in nanoscience and nanotechnology and expertise of recent faculty hires.

APPROVED FOR THE FACULTY OF THE SCHOOLS OF ENGINEERING BY THE ENGINEERING CURRICULUM COMMITTEE

ECC Minutes

Chairman ECC

Keith J. Bowman, Professor and Head School of Materials Engineering

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MSE 270

Atomistic Materials Science

Instructors:

Alejandro Stachan, strachan@purdue.edu, ARMS 2229, 496-3551

Eric Stach, eastach@purdue.edu, BRK 1299, 494-1466

Course Description: Introductory course with an atomistic viewpoint on material properties. Three primary class sections: bonding, crystallography and statistical mechanics. Bonding topics include introduction to quantum mechanics, emphasis on understanding of metallic, ionic and covalent bonding. Crystallography topics include crystal descriptions and symmetry principles. Statistical mechanics developed with application to electronic and thermodynamic properties.

Prerequisite: MA 261 and MA 265; Corequisite: MSE 230 or consent of instructor.

Goals: Students will learn introductory level concepts in quantum mechanics and use these to develop an increased understanding of bond formation in molecules and solids. The role of bonding in crystal structure will be explored, with and emphasis formal classification of crystal structure and crystal symmetry. The effect so temperature on crystal structure and properties will be explained through the use of stastical mechanics concepts.

Objectives:

1. All Students

A. Understand the origins of metallic, covalent and ionic bonding

- · Schrödinger's Equation and its solution for simple situations
- · Origin of cohesive energies and relationship with elastic constants
- · Descriptions of metallic, covalent and ionic bonding
- B. Understand how symmetry in materials leads to crystal structure
- Be able to identify symmetry elements, such as mirror planes, rotation axes, glide planes and screw axes
- Identity the underlying symmetry elements in specific crystallographic point and space groups
- C. Are able to describe crystal classes, crystal directions and lattice planes
- · Describe crystal directions and lattice planes using Miller indices
- · Describe unit cells and lattices
- D. Understand the origin of statistical expressions of population occupancy
- Show how different assumptions about the character of a population lead to different occupancies of energy levels
- · Correlate statistical distributions of occupied energy levels with internal energy, entropy and free energy

2. Most Students

- A. Have an understanding of the underlying origins of bonding
- Show how solution of the Schrödinger Equation for the hydrogen atom can be expanded to atoms with more than one proton, leading to the periodic table of the elements
- Understand the origin of cohesive energy in ionic crystals
- Understand how wave function overlaps lead to molecular orbitals and covalent bonding, and why these bonds are both directional and strong
- Understand how state splitting provides an intuitive understanding of crystal bands and metallic bonding
- B. Understand how particular combinations of crystal symmetry lead to specific point and space groups
- C. Utilize the stereographic projection to relate planes and directions in a crystal

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D. Understand how statistical descriptions of energy states lead to material properties such as heat capacity and specific heat.

3. Some Students

A. Are able to utilize the information in the International Tables of Crystallography to create models of a crystal structure

- B. Correlate the existence of anisotropy in materials with specific bonding characteristics
- C. Correlate changes in temperature with changes in thermodynamic quantities

Textbook

"Crystals and Crystal Structure", R. Tilley, John Wiley & Sons, West Sussex, England, 2006.

Assessment: Class participation (5%), Homework (15%), Exams (80%) [Two exams (25%) & Comprehensive final (30%)]

Instructors: Alejandro Strachan, Eric Stach, Eric Kvam

Spring 2008 - Syllabus

Date	Topic
1/07 (M)	Context, Perspective and Organization. Intro to bonding
Part I: Bonding	& Crustal Binding
1/09 (W)	Why do we need quantum mechanics? The hydrogen atom
1/11 (F)	Quantum mechanics: postulates and the Schrödinger Eq.
1/14 (M)	Solutions of the Schrödinger Eq: square well + hydrogen atom
1/16 (W)	Electronic structure of atoms: energy levels, wave functions
1/18 (F)	Electronic structure of atoms: 1 st and 2 nd rows
1/21 (M)	University Holiday – no class
1/23 (W)	Electronic structure & bonding in molecules: H2+
1/25 (F)	Elect. Struct. & bonding in molecules: bonding and anti-bonding
1/28 (M)	Elect. Struct. & bonding in molecules: 1st row hydrides
1/30 (W)	Elect. Struct. & bonding in molecules: 1° row hydrides
2/1 (F)	Elect. Struct. & bonding in molecules: ionic bonding
2/4 (M)	Elect. Struct. & bonding in molecules: van der Waals
2/6 (W)	Electronic structure & bonding in crystals: bands
2/8 (F)	Elect. Struct. & bonding in crystals: bands
2/11 (M)	Elect. Struct. & bonding in crystals: covalent vs. metallic bonding
2/13 (W)	Elect. Struct. & bonding in crystals: covalent vs. metallic bonding
2/15 (F)	Review of Part I
2/18 (M)	Midterm #1
Part II: Symm	etry, Crystal structure and Crystallography
2/20 (W)	Relationship between bonding and crystal structure
2/22 (F)	External crystal forms: mineralogy and the origins of crystallography
2/25 (M)	Elements of Symmetry; 2-D Unit Cells and Asymmetric Units
2/27 (W)	Coordinates; Directions; Lattices; Symmetry Groups in 2D

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2 (2 (14)	Rational Directions; Weiss Zone Law; Miller-Bravais Indices
3/3 (M)	32 Crystallographic Point Groups; Bravais Lattices
3/5 (W)	Glide Planes; Screw Axes
3/7 (F)	
3/10 (M)	Spring Break – no class
3/12 (W)	Spring Break – no class
3/14 (F)	Spring Break – no class
3/10 (M)	Using the International Tables of Crystallography
3/19 (W)	Creating Crystal Structures with Software Tools (CrystalMaker)
3/21 (F)	The Stereographic Projection - Construction & Uses
3/24 (M)	The Stereographic Projection - Construction & Uses
3/26 (W)	Tensors & Tensor Description of Materials Properties
3/28 (F)	Review of Part II
3/31 (M)	Midterm #2
Part III: Therm	al properties & Statistical Mechanics
4/2 (W)	Motivation / Elementary Statistical Concepts
4/4 (F)	Population of Energy States (Partition Functions)
4/7 (M)	Distinguishable Particles – Maxwell-Boltzman statistics
4/9 (W)	Distinguishable Particles – Maxwell-Boltzman statistics (continued)
4/11 (F)	Indistinguishable Particles - Bose-Einstein statistics
4/14 (M)	Indistinguishable particles – Fermi-Dirac statistics
4/16 (W)	Relationship between stat. mech. & thermodynamic quantities
4/18 (F)	Relationship between stat. mech. & thermodynamic quantities (continued)
4/21 (M)	Phonons
4/23 (W)	Heat transfer and heat capacity
4/25 (F)	Review of Part III

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